

CGS2535V/CGS2535TV Commercial Quad 1 to 4 Clock Drivers/Industrial Quad 1 to 4 Clock Drivers

Check for Samples: [CGS2535TV](#), [CGS2535V](#)

FEATURES

- **Ensured:**
 - **1.0 ns Rise and Fall Times While Driving 12 Inches of 50Ω Microstrip Terminated with 25 pF**
 - **350 ps Pin-to-Pin Skew (t_{OSLH} and t_{OSHL})**
- **650 ps Part-to-Part Variation on Positive or Negative Transition @ 5V V_{CC}**
- **Operates with Either 3.3V or 5.0V Supply**
- **Inputs 5V Tolerant with V_{CC} in 3.3V Range**
- **Symmetric Output Current Drive: 24 mA I_{OH}/I_{OL}**
- **Industrial Temperature Range -40°C to $+85^{\circ}\text{C}$**
- **Symmetric Package Orientation**
- **Large Fanout for Memory Driving Applications**
- **Ensured 2 kV ESD Protection**
- **Implemented on TI's ABT Family Process**
- **28-pin PLCC for Optimum Skew Performance**

DESCRIPTION

These Clock Generation and Support clock drivers are specifically designed for driving memory arrays requiring large fanouts while operating at high speeds.

The CGS2535 is a non-inverting 4 to 16 driver with CMOS I/O structures. The CGS2535 specification ensured part-to-part skew variation.

Connection Diagrams

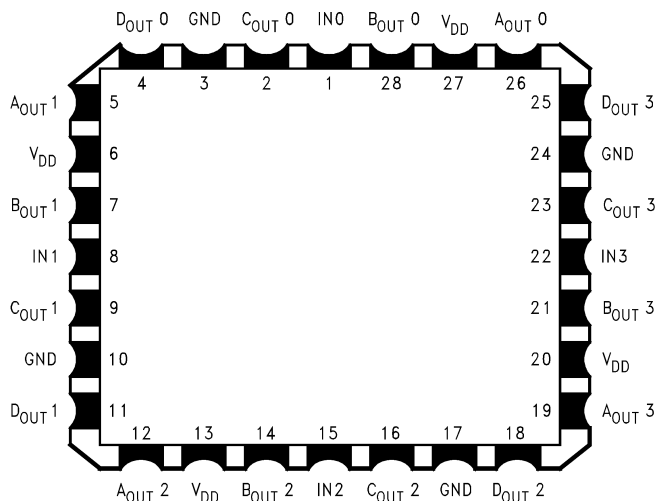


Figure 1. Pin Assignment for 28-Pin PLCC

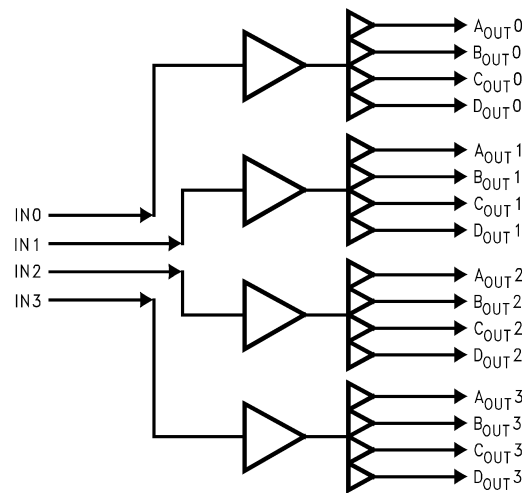


Figure 2. CGS2535

Truth Table

Input	Output
In (0–3)	ABCD Out (0–3)



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

Supply Voltage (V_{CC})		7.0V
Input Voltage (V_I)		7.0V
Input Current		–30 mA
Current Applied to Output (High/Low)		Twice the Rated I_{OH}/I_{OL}
Operating Temp.	Industrial grade	–40°C to +85°C
	Comm. grade	0°C to +70°C
Storage Temperature Range (–65°C to +150°C)	Airflow	Typical θ_{JA}
	0 LFM	62°C/W
	225 LFM	43°C/W
	500 LFM	34°C/W
	900 LFM	27°C/W

- (1) The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be ensured. The device should not be operated at these limits. The parametric values defined in the DC and AC Electrical Characteristics tables are not ensured at the absolute maximum ratings. The Recommended Operating Conditions will define the conditions for actual device operation.

Recommended Operating Conditions

Supply Voltage		V_{CC} 4.75V to 5.25V
		V_{CC} 3.0V to 3.6V
Maximum Input Rise/Fall Time	(0.8V to 2.0V)	5 ns
Free Air Operating Temperature	Commercial	0°C to + 70°C
	Industrial	–40°C to + 85°C

DC Electrical Characteristics

Over recommended operating free air temperature range. All typical values are measured at $V_{CC} = 5V$, $T_A = 25^\circ C$.

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Typ	Max	Units
V_{IH}	Input High Level Voltage		3.0	2.1			V
			4.5	3.15			
			5.5	3.85			
V_{IL}	Input Low Level Voltage		3.0			0.9	V
			4.5			1.35	
			5.5			1.65	
V_{IK}	Input Clamp Voltage	$I_I = -18\text{ mA}$	4.5			-1.2	V
V_{OH}	High Level Output Voltage	$I_{OH} = -50\text{ }\mu A$	3.0	2.9			V
			4.5	4.4			
			5.5	5.4			
		$I_{OH} = -24\text{ mA}$	3.0	2.46			V
			4.5	3.76			
			5.5	4.76			
V_{OL}	Low Level Output Voltage	$I_{OL} = 50\text{ }\mu A$	3.0			0.1	V
			4.5			0.1	
			5.5			0.1	
		$I_{OL} = 24\text{ mA}$	3.0			0.44	V
			4.5			0.44	
			5.5			0.44	
I_I	Input Current @ Max Input Voltage	$V_{IH} = 7V$	5.5			7	μA
		$V_{IH} = V_{CC}$	3.6			1	
I_{IH}	High Level Input Current	$V_{IH} = V_{CC}$	5.5			5	μA
I_{IL}	Low Level Input Current	$V_{IL} = 0V$	5.5	-5			μA
I_{OLD}	Minimum Dynamic Output Current ⁽¹⁾	$V_{OLD} = 1.65V\text{ (max)}$	5.5	75			mA
		$V_{OLD} = 0.9V\text{ (max)}$	3.0 ⁽²⁾	36			
I_{OHD}	Minimum Dynamic Output Current ⁽¹⁾	$V_{OHD} = 3.85V\text{ (min)}$	5.5	-75			mA
		$V_{OHD} = 2.1V\text{ (min)}$	3.0 ⁽²⁾	-25			
I_{CC}	Supply Current		3.6			75	μA
			5.5			235	
C_{IN}	Input Capacitance		5.0		5		pF

(1) Maximum test duration 2.0 ms, one output loaded at a time.

(2) At $V_{CC} = 3.3V$, $I_{OLD} = 55\text{ mA min}$; @ $V_{CC} = 3.6V$, $I_{OLD} = 64\text{ mA min}$
At $V_{CC} = 3.3V$, $I_{OHD} = -58\text{ mA min}$; @ $V_{CC} = 3.6V$, $I_{OHD} = -66\text{ mA min}$

AC Electrical Characteristics⁽¹⁾⁽²⁾⁽³⁾

Over recommended operating free air temperature specified. All typical values are measured at $V_{CC} = 5V$, $T_A = 25^\circ C$.

Symbol	Parameter	V _{CC} (V) ⁽⁴⁾	CGS2535						Units
			T _A = +25°C			T _A = -40°C to +85°C ⁽⁵⁾			
			C _L = 50 pF, R _L = 500Ω			C _L = 50 pF, R _L = 500Ω			
			Min	Typ	Max	Min	Typ	Max	
f _{max}	Frequency Maximum	3.0 5.0					100 125		MHz
t _{PLH}	Low-to-High Propagation Delay CK to O _n @ 1 MHz ⁽⁶⁾	3.3 5.0			4.5 3.5	2.5 2.0		4.5 3.5	ns
t _{PHL}	High-to-Low Propagation Delay CK to O _n @ 1 MHz ⁽⁶⁾	3.3 5.0			4.5 3.5	2.5 2.0		4.5 3.5	ns
t _{PLH}	Low-to-High Propagation Delay CK to O _n @ 66.67 MHz ^{(6) (7)}	3.3 5.0			5.0 4.5	2.5 2.0		5.0 4.5	ns
t _{PHL}	High-to-Low Propagation Delay CK to O _n @ 66.67 MHz ^{(6) (7)}	3.3 5.0			5.0 4.5	2.5 2.0		5.0 4.5	ns
t _{OSLH}	Maximum Skew Common Edge Output-to-Output Variation ^{(1) (3)}	3.3 5.0		150 150	350 350		300 300	350 350	ps
t _{OSHL}	Maximum Skew Common Edge Output-to-Output Variation ^{(1) (3)}	3.3 5.0		150 150	350 350		300 300	350 350	ps
t _{rise} , t _{fall}	Rise/Fall Time (from 0.8V/2.0V to 2.0V/0.8V) ⁽⁸⁾	3.3 5.0			3.5 3.0			3.5 3.0	ns
t _{rise} , t _{fall}	Rise/Fall Time (from 0.8V/2.0V to 2.0V/0.8V) ^{(7) (9)}	3.3 5.0			0.8 0.4			1.0 0.6	ns
t _{rise} , t _{fall}	Rise/Fall Time (from 0.8V/2.0V to 2.0V/0.8V) ^{(7) (10)}	3.3 5.0			1.0 0.7			1.0 0.9	ns
t _{High}	Pulse Width Duration High ^{(2) (3) (7)}	3.3 5.0	4.0 4.0			4.0 4.0			ns
t _{Low}	Pulse Width Duration Low ^{(2) (3) (7)}	3.3 5.0	4.0 4.0			4.0 4.0			
t _{PVLH}	Part-to-Part Variation of Low-to-High Transitions @ 1 MHz ⁽⁶⁾	3.3 5.0			650 650			1.0 650	ns ps
t _{PVHL}	Part-to-Part Variation of High-to-Low Transitions @ 1 MHz ⁽⁶⁾	3.3 5.0			650 650			1.0 650	ns ps
t _{PVLH}	Part-to-Part Variation of Low-to-High Transitions @ 66.67 MHz ^{(6) (7)}	3.3 5.0			1.0 1.0			1.0 1.0	ns
t _{PVHL}	Part-to-Part Variation of High-to-Low Transitions @ 66.67 MHz ^{(6) (7)}	3.3 5.0			1.0 1.0			1.0 1.0	

- (1) Output-to-Output Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device and output bank. The specifications apply to any outputs switching in the same direction either LOW to HIGH (t_{OSLH}) or HIGH to LOW (t_{OSHL}).
- (2) Time high is measured with outputs at 2.0V or above. Time low is measured with outputs at 0.8V or below. Input waveform characteristics for t_{High} , t_{Low} measurement: $f = 66.67$ MHz, duty cycle = 50%.
- (3) The input waveform has a rise and fall time transition time of 2.5 ns (10% to 90%).
- (4) Voltage Range 5.0 is $5.0V \pm 0.25V$, 3.3 is $3.3V \pm 0.3V$.
- (5) Industrial range ($-40^\circ C$ to $+85^\circ C$) limits apply to the commercial temperature range ($0^\circ C$ to $+70^\circ C$).
- (6) All 16 outputs switching simultaneously.
- (7) Ensured by design.
- (8) These Rise and Fall times are measured with $C_L = 50$ pF, $R_L = 500\Omega$ (see [Figure 4](#)).
- (9) These Rise and Fall times are measured with $C_L = 25$ pF, $R_L = 500\Omega$ (see [Figure 4](#)), and are ensured by design.
- (10) These Rise and Fall times are measured driving 12 inches of 50 Ω microstrip terminated with equivalent $C_L = 25$ pF (see [Figure 5](#)), and are ensured by design.

Timing Information

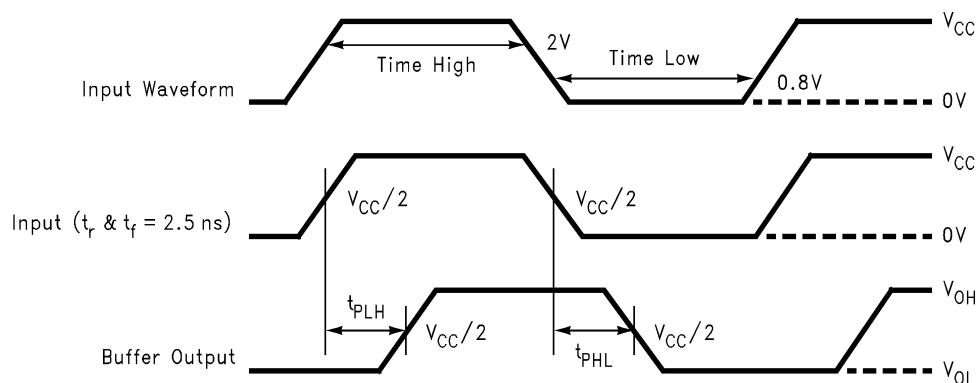
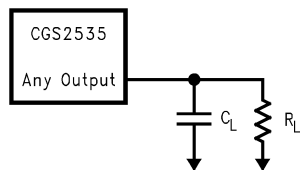


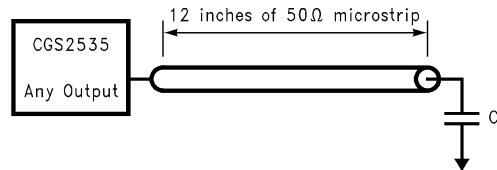
Figure 3.



These Rise and Fall times are measured with $C_L = 50$ pF, $R_L = 500\Omega$ (see [Figure 4](#)).

These Rise and Fall times are measured with $C_L = 25$ pF, $R_L = 500\Omega$ (see [Figure 4](#)), and are ensured by design.

Figure 4. A.C. Load
 C_L = Total Load Including Probes



These Rise and Fall times are measured driving 12 inches of 50Ω microstrip terminated with equivalent $C_L = 25$ pF (see [Figure 5](#)), and are ensured by design.

Figure 5. A.C. Load
 C_L = Total Load Including Probes

CGS2534/35/36/37

MEMORY ARRAY DRIVING

In order to minimize the total load on the address bus, quite often memory arrays are driven by buffers while having the inputs of the buffers tied together. Although this practice was feasible in the conventional memory designs, in today's high speed, large buswidth designs which require address fetching at higher speeds, this technique produces many undesired results such as cross-talk and over/undershoot.

CGS2534/35/36/37 Quad 1 to 4 clock drivers were designed specifically to address these application issues on high speed, large memory arrays systems.

These drivers are optimized to drive large loads, with 3.5 ns propagation delays. These drivers produce less noise while reducing the total capacitive loading on the address bus by having only four inputs tied together (see [Figure 6](#), point A). This helps to minimize the overshoot and undershoot by having only four outputs being switched simultaneously.

Also this larger fan-out helps to save board space since for every one of these drivers, two conventional buffers were typically being used.

Another feature associated with these clock drivers is a 350 ps pin-to-pin skew specification. The minimum skew specification allows high speed memory system designers to optimize the performance of their memory subsystem by operating at higher frequencies without having concerns about output-to-output (bank-to-bank) synchronization problems which are associated with driving high capacitive loads (Point B).

The diagram below depicts a “2534/35/36/37” a memory subsystem operating at high speed with large memory capacity. The address bus is common to both the memory and the CPU and I/Os.

These drivers can operate beyond 125 MHz, and are also available in 3V–5V TTL/CMOS versions with large current drive .

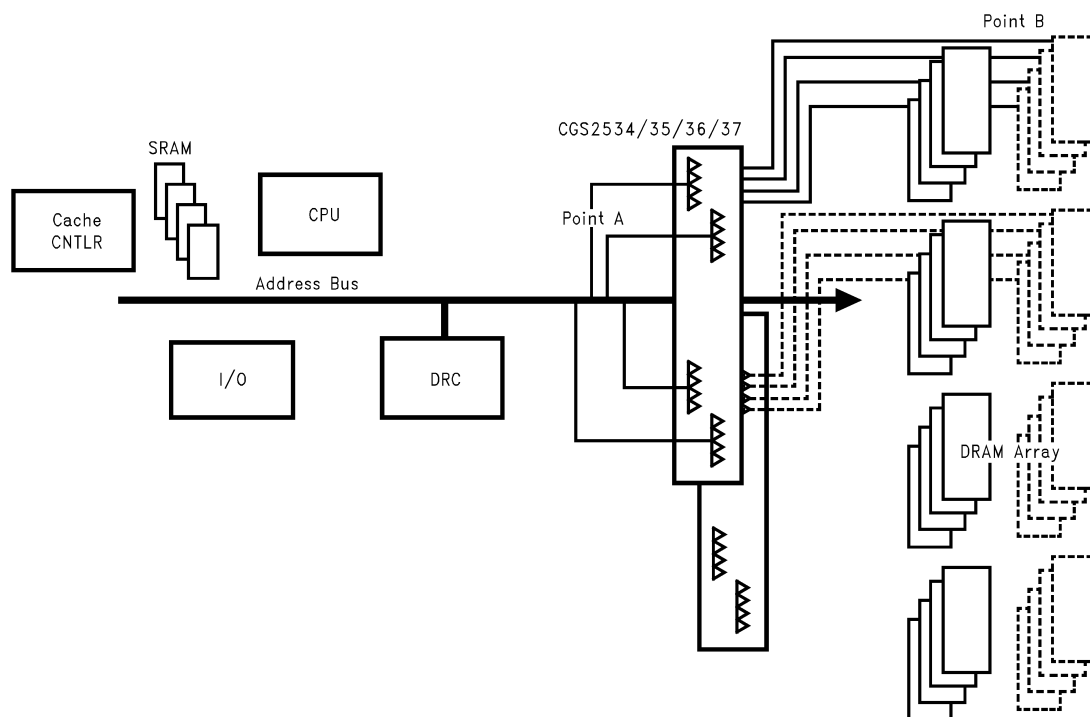


Figure 6. “2534/35/36/37”

Device	V _{CC}	I/O	Output Configuration
2534	5	TTL	Inverting quad 1–4
2535	3 or 5	CMOS	Non-inverting quad 1–4
2536	3 or 5	CMOS	Inverting, Non-inverting, ÷2
2537	5	TTL	Inverting quad 1–4 with series 8Ω output resistors

Part Numbering Information



REVISION HISTORY

Changes from Revision B (April 2013) to Revision C

Page

- Changed layout of National Data Sheet to TI format [7](#)

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